# ZPT-2012C-10-Z3

#### **0805** Package Phototransistor

#### **Descriptions**

ZPT-2012C-10-Z3 is a phototransistor in miniature SMD package which is molded in a water clear with flat top view lens.

The device is Spectrally matched to visible and infrared emitting diode.

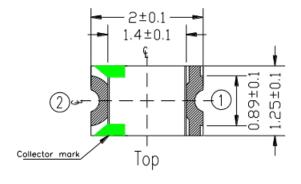
#### **Features**

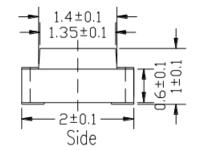
- Fast response time
- High photo sensitivity
- Small junction capacitance
- Pb free
- The product itself will remain within RoHS compliant version.
- Compliance with EU REACH

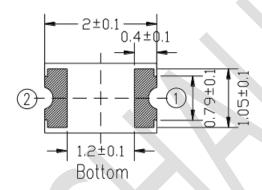
### **Applications**

- Miniature switch
- Counters and sorter
- Position sensor
- Infrared applied system
- Encoder

### **Package Dimensions**



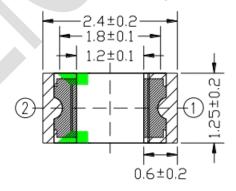




- 1 Eimmiter
- (2) Collector



Recommend Sodering Pad



Notes: 1. All dimensions are in millimeters

- 2. Tolerances unless dimensions  $\pm 0.1$  mm
- 3. Suggested pad dimension is just for reference only

Please modify the pad dimension based on individual need

# **Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Rating	Units V	
Collector-Emitter Voltage	V <sub>CEO</sub>	30		
Emitter-Collector-Voltage	V <sub>ECO</sub>	5	V	
Collector Current	lc	20	mA	
Operating Temperature	Topr	-25 ~ +85	$^{\circ}$ C	
Storage Temperature	T <sub>stg</sub>	-40 ~ +85	$^{\circ}$ C	
Soldering Temperature *1	T <sub>sol</sub>	260	$^{\circ}\! \mathbb{C}$	
Power Dissipation at(or below) 25℃ Free Air Temperature	P <sub>d</sub>	75	mW	

Notes: \*1:Soldering time ≤ 5 seconds.

# Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Rang Of Spectral Bandwidth	λ <sub>0.5</sub>		400		1100	nm
Wavelength Of Peak Sensitivity	$\lambda_{P}$			940		nm
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =100μA Ee=0mW/cm <sup>2</sup>	30		I	<b>V</b>
Emitter-Collector Breakdown Voltage	BV <sub>ECO</sub>	I <sub>E</sub> =100μA Ee=0mW/cm²	5			<b>V</b>
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =2mA Ee=1mW/cm <sup>2</sup>			0.4	V
Collector Dark Current	I <sub>CEO</sub>	V <sub>CE</sub> =20V Ee=0mW/cm <sup>2</sup>	-		100	nA
On State Collector Current	I <sub>C(ON)</sub>	V <sub>CE</sub> =5V Ee=1mW/cm <sup>2</sup>	0.3	1.0		mA

## **Typical Electro-Optical Characteristics Curves**

Fig.1 Spectral Sensitivity

1.0

T a = 25 °C

Vinition

O.8

0.8

0.6

0.4

0.2

0.0

100 300 500 700 900 1100 1300

Wavelength λ (nm)

Fig.2 Collector Current vs Irradiance

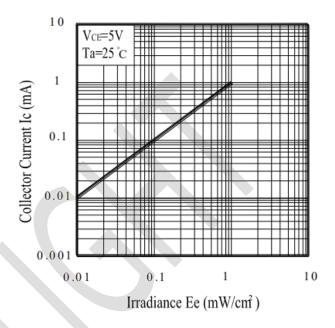
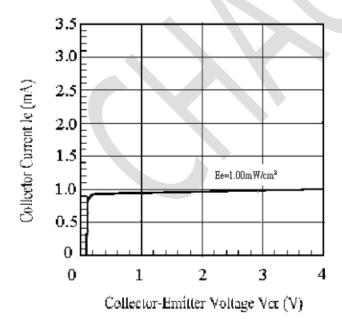
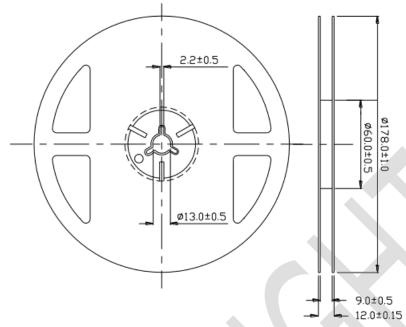


Fig.3 Collector Current vs.

Collector-Emitter Voltage

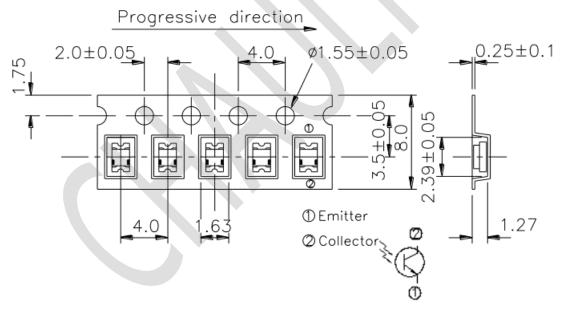


# **Package Dimensions**



**Note:** The tolerances unless mentioned are ±0.1mm, Unit: mm

Carrier Tape Dimensions: (Loaded Quantity: 3000pcs/reel)



Note: The tolerances unless mentioned is ±0.1mm, Unit = mm